

Non Magnetic SMQ HIPAX PIN Diode

Rev. V2

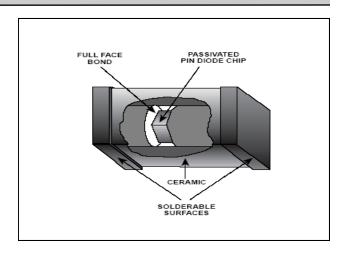
Features

- Non-Magnetic Package Suitable for MRI **Applications**
- Rectangular MELF SMQ Ceramic Package
- Hermetically Sealed
- Lower Rs for Lower Series Loss
- Longer τ_L for Lower Intermodulation Distortion
- Lower Cj for Higher Series Isolation
- Higher Average Incident Power Handling Capability

Description and Applications

The MA4P7452F-1072T is a surface mountable PIN diode in a Non-Magnetic (patent pending) Metal Electrode Leadless Faced (MELF) package. The device incorporates M/A-COM's proven HIPAX technology to produce a low inductance ceramic package with no ribbons or whisker wires. The package utilizes M/A-COM's new non- magnetic plating process to provide an extremely low permeability, hermetically sealed package. Incorporated in the package is a passivated PIN diode that is full face bonded on both the cathode and anode of the chip to maximize surface area for lower electrical and thermal resistance. The MA4P7452F-1072T has been comprehensively characterized both electrically and mechanically to ensure repeatable and predictable performance. This MA4P7452F-1072T Non-Magnetic device is electrical performance similar in to MA4P7002F-1072T Magnetic part number.

The diodes are well suited for use in low loss, low distortion, and high power switching circuits applicable for high magnetic field environments from HF through UHF frequencies. The lower thermal resistance of this device provides excellent higher average performance at RF power incident levels up to 100 watts CW. This device is designed to meet the most rigorous electrical and mechanical requirements of MRI testing environments.



Designed for Automated Assembly

These SMQ PIN diodes are designed for high volume tape and reel assembly. The rectangular package design provides for highly efficient automatic pick and place assembly techniques. The parallel flat surfaces are suitable for key jaw or vacuum pickup techniques. All solder able surfaces are tin plated and compatible with reflow and vapor phase soldering methods.



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Enviornmental Capability

HIPAX devices are applicable for use in industrial and military applications and can be screened to environmental requirements MIL-STD-750, MIL-STD-202 as well as other military standards. The table below lists some of the MIL-STD 750 tests the device is designed to meet.

MIL-STD-750				
Test	Method	Description		
High Temperature Storage	1031	+150 °C, for 340 Hours		
Temperature Shock	1051	-65 °C to +125 °C, 20 Cycles		
HTRB	1038	80% of rated V _B , +150 °C, for 96 Hours		
Moisture Resistance	1021	No Initial Conditioning, 85 % RH, +85° C		
Gross Leak	1071 Cond. E	Dye Penetrant Visual		
Vibration Fatigue	2046	20,000 G's, 60 Hz, x, y, z axis		
Solderability	2026	Test Temperature = +245 °C		

Ordering Information

Part Number	Package
MA4P7452F-1072T	Tape and Reel



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Electrical Specifications @ +25 °C

Parameter	Symbol	Condition	Unit Value
Forward Voltage (Maximum)	V_{F}	I _F = +100 mA	1.0 V _{DC}
Voltage Rating (Minimum)	V_R	Ir = -10 uA	I – 150 I V _{DC}
Total Capacitance (Maximum)	Ст	-100 V @ 100 MHz	0.7 pF
Series Resistance (Maximum)	R _S	+100 mA @ 100 MHz	0.9 Ohms
Parallel Resistance (Minimum)	R_{P}	-10 V @ 100 MHz	75 K Ω
Carrier Lifetime (Nominal)	τι	+6 mA / -10 mA @ (50% - 90% Voltage)	9 <i>u</i> s
I-Region Length (Nominal)	μm	-	175 μm
C.W. Thermal Resistance (Maximum)	θ	$I_H = 1A, I_L = 10 \text{ mA},$ T = 1 mS	15 °C/W
Power Dissipation in Free Air (Maximum)	W	I _F = +100 mA	4 W
Power Dissipation with Diode Case at Tambient (Maximum)	P _D	I _F = +100 mA	10 W

Absolute Maximum Ratings¹ @ 25°C

Parameter	Absolute Maximum
Operating Temperature	-65 °C to +125 °C
Storage Temperature	-65 °C to +150 °C
Diode Junction Temperature	+175 °C Continuous
Diode Mounting Temperature	+235 °C for 10 seconds
RF C.W. Incident Power	+ 50 dBm C.W.
Forward D.C. Current	+ 250 mA
Reverse D.C. Voltage @ -10 uA	I - 200 V I

^{1.} Exceeding these limits may cause permanent damage.

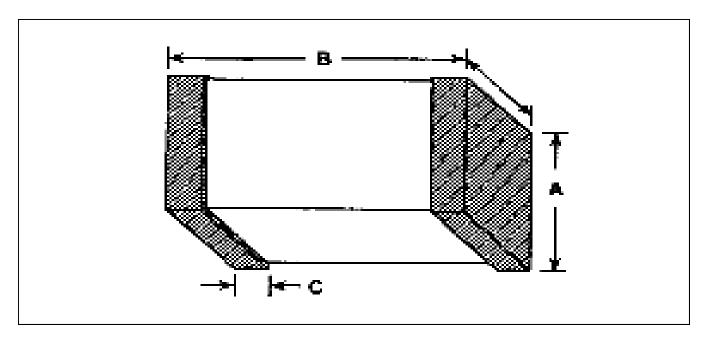


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Mechanical Outline

Case Style	Dimensions in Inches (<i>mm</i>)		
	A Square	B	C
	Min / Max	Min / Max	Min / Max
1072	0.080 / 0.095	0.115 / 0.135	0.008 / 0.030
	(2.03 / 2.41)	(2.92/ 3.43)	(.203 / .762)



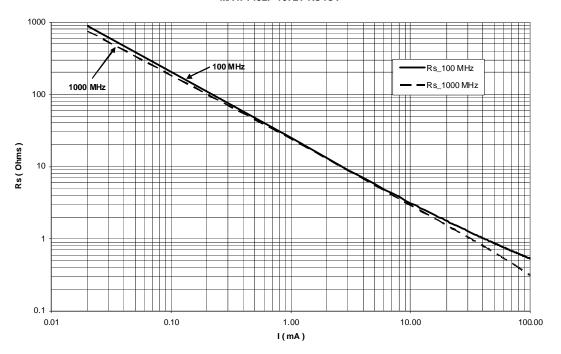


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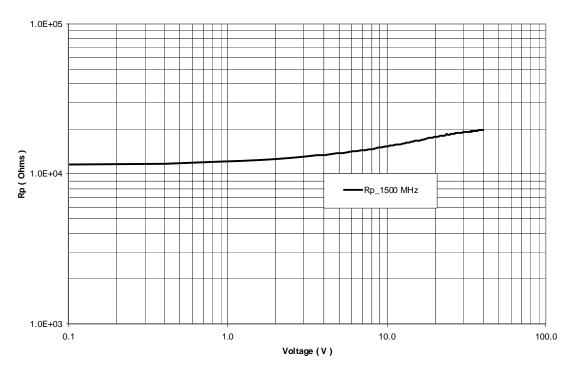
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Typical Electrical Performance

MA4P7452F-1072T Rs vs I



MA4P7452F-1072T Rp vs Voltage



typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

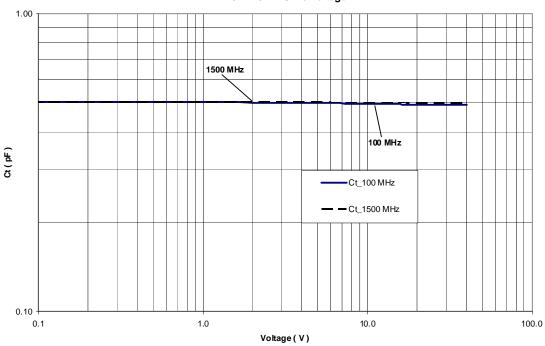


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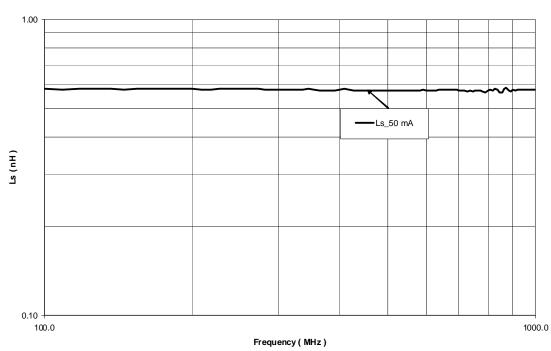
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Typical Electrical Performance

MA4P7452F-1072T Ct vs Voltage



MA4P7452F-1072T Ls vs Frequency



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Typical Non-Magnetic Performance

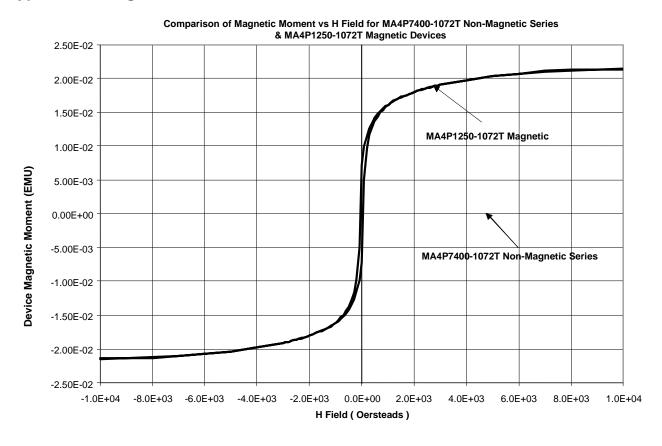


Table 1 - Typical Magnetic Properties of Non-Magnetic MA4P7452F-1072T Device Vs. Conventional MA4P1250F-1072T Magnetic Device

Magnetic Property	MA4P7441F-1091T Value	MA4P4001-1091T Value
Saturation Moment (EMU) @ H = H _{MAX} Oersteads	2.3 x E-4	2.1 x E-2
Remanance Moment (EMU) @ H = 0 Oersteads	4.2 x E-8	7.1 x E-3
Coercivity (Oersteads) @ EMU = 0 Moment	1.0	59.2

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